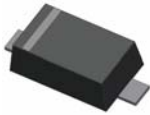


**Small Signal Diode**



**Features**

- ◇Wide zener voltage range selection : 2.4V to 75V
- ◇Vz Tolerance Selection of ±2%
- ◇Moisture sensitivity level 1
- ◇Matte Tin(Sn) lead finish with Nickel(Ni) underplate
- ◇Pb free version and RoHS compliant
- ◇Green compound (Halogen free) with suffix "G" on packing code and prefix "G" on date code

**Mechanical Data**

- ◇Case : Flat lead SOD-323 small outline plastic package
- ◇Terminal: Matte tin plated, lead free., solderable per MIL-STD-202, Method 208 guaranteed
- ◇High temperature soldering guaranteed: 260°C/10s
- ◇Polarity : Indicated by cathode band
- ◇Weight : 4.02±0.5 mg

**Ordering Information**

Part No.	Package	Packing
BZT52BxxS RR	SOD-323F	3Kpcs / 7" Reel

**Maximum Ratings and Electrical Characteristics**

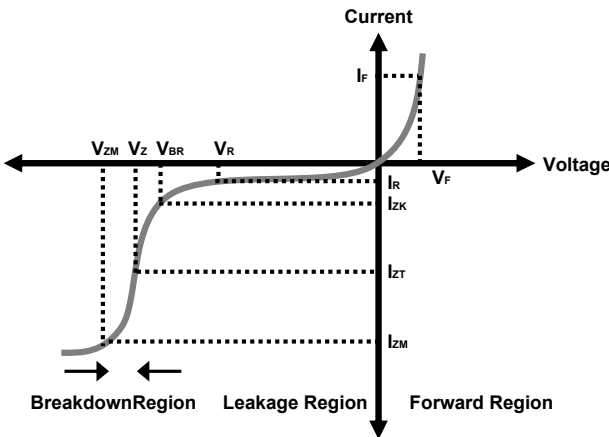
Rating at 25°C ambient temperature unless otherwise specified.

**Maximum Ratings**

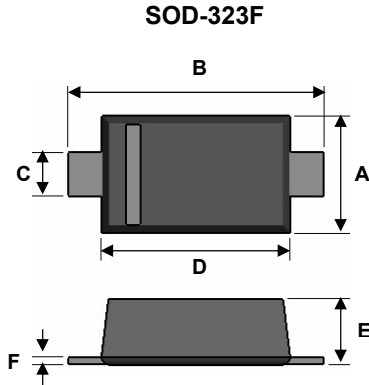
Type Number	Symbol	Value	Units
Power Dissipation	$P_D$	200	mW
Forward Voltage	$V_F$	1	V
Thermal Resistance (Junction to Ambient)	$R_{\theta JA}$	625	°C/W
Junction and Storage Temperature Range	$T_J, T_{STG}$	-65 to + 150	°C

Notes:1. Valid provided that electrodes are kept at ambient temperature

**Zener I vs. V Characteristics**



- $V_{BR}$  : Voltage at  $I_{ZK}$
- $I_{ZK}$  : Test current for voltage  $V_{BR}$
- $Z_{ZK}$  : Dynamic impedance at  $I_{ZK}$
- $I_{ZT}$  : Test current for voltage  $V_Z$
- $V_Z$  : Voltage at current  $I_{ZT}$
- $Z_{ZT}$  : Dynamic impedance at  $I_{ZT}$
- $I_{ZM}$  : Maximum steady state current
- $V_{ZM}$  : Voltage at  $I_{ZM}$



Dimensions	Unit (mm)		Unit (inch)	
	Min	Max	Min	Max
A	1.15	1.35	0.045	0.053
B	2.30	2.70	0.091	0.106
C	0.25	0.40	0.010	0.016
D	1.60	1.80	0.063	0.071
E	0.80	1.00	0.031	0.039
F	0.05	0.20	0.002	0.008

### Small Signal Diode

#### Electrical Characteristics

Ta = 25°C unless otherwise noted

VF Forward Volatge = 1 V Maximum @ IF = 10mA for all part numbers

Part Number	Device Marking	Vz @ IZT (Volt)			IZT (mA)	ZZT @ IZT (Ω) Max	IZK (mA)	ZZK @ IZK (Ω) Max	IR @ VR (μA) Max	VR (V)
		Min	Nom	Max						
BZT52B2V4S	0Z	2.35	2.40	2.45	5	100	1	564	45	1
BZT52B2V7S	1Z	2.65	2.70	2.75	5	100	1	564	18	1
BZT52B3V0S	2Z	2.94	3.00	3.06	5	100	1	564	9	1
BZT52B3V3S	3Z	3.23	3.30	3.37	5	95	1	564	4.5	1
BZT52B3V6S	4Z	3.53	3.60	3.67	5	90	1	564	4.5	1
BZT52B3V9S	5Z	3.82	3.90	3.98	5	90	1	564	2.7	1
BZT52B4V3S	6Z	4.21	4.30	4.39	5	90	1	564	2.7	1
BZT52B4V7S	7Z	4.61	4.70	4.79	5	80	1	470	2.7	2.0
BZT52B5V1S	8Z	5.00	5.10	5.20	5	60	1	451	1.8	2.0
BZT52B5V6S	9Z	5.49	5.60	5.71	5	40	1	376	0.9	2.0
BZT52B6V2S	AZ	6.08	6.20	6.32	5	10	1	141	2.7	4.0
BZT52B6V8S	BZ	6.66	6.80	6.94	5	15	1	75	1.8	4.0
BZT52B7V5S	CZ	7.35	7.50	7.65	5	15	1	75	0.9	5.0
BZT52B8V2S	DZ	8.04	8.20	8.36	5	15	1	75	0.63	5.0
BZT52B9V1S	EZ	8.92	9.10	9.28	5	15	1	94	0.45	6.0
BZT52B10S	FZ	9.80	10.00	10.20	5	20	1	141	0.18	7.0
BZT52B11S	GZ	10.78	11.00	11.22	5	20	1	141	0.09	8.0
BZT52B12S	HZ	11.76	12.00	12.24	5	25	1	141	0.09	8.0
BZT52B13S	JZ	12.74	13.00	13.26	5	30	1	160	0.09	8.0
BZT52B15S	KZ	14.70	15.00	15.30	5	30	1	188	0.045	10.5
BZT52B16S	LZ	15.68	16.00	16.32	5	40	1	188	0.045	11.2
BZT52B18S	MZ	17.64	18.00	18.36	5	45	1	212	0.045	12.6
BZT52B20S	NZ	19.60	20.00	20.40	5	55	1	212	0.045	14.0
BZT52B22S	PZ	21.56	22.00	22.44	5	55	1	235	0.045	15.4
BZT52B24S	RZ	23.52	24.00	24.48	5	70	1	235	0.045	16.8
BZT52B27S	SZ	26.46	27.00	27.54	2	80	0.5	282	0.045	18.9
BZT52B30S	TZ	29.40	30.00	30.60	2	80	0.5	282	0.045	21.0
BZT52B33S	UZ	32.34	33.00	33.66	2	80	0.5	306	0.045	23.0
BZT52B36S	VZ	35.28	36.00	36.72	2	90	0.5	329	0.045	25.2
BZT52B39S	WZ	38.22	39.00	39.78	2	130	0.5	329	0.045	27.3
BZT52B43S	XZ	42.14	43.00	43.86	2	150	0.5	353	0.045	30.1
BZT52B47S	YZ	46.06	47.00	47.94	2	170	0.5	353	0.045	33.0
BZT52B51S	-Z	49.98	51.00	52.02	2	180	0.5	376	0.045	35.7
BZT52B56S	=Z	54.88	56.00	57.12	2	200	0.5	400	0.045	39.2
BZT52B62S	≡Z	60.76	62.00	63.24	2	215	0.5	423	0.045	43.4
BZT52B68S	>Z	66.64	68.00	69.36	2	240	0.5	447	0.045	47.6
BZT52B75S	<Z	73.50	75.00	76.50	2	255	0.5	470	0.045	52.5

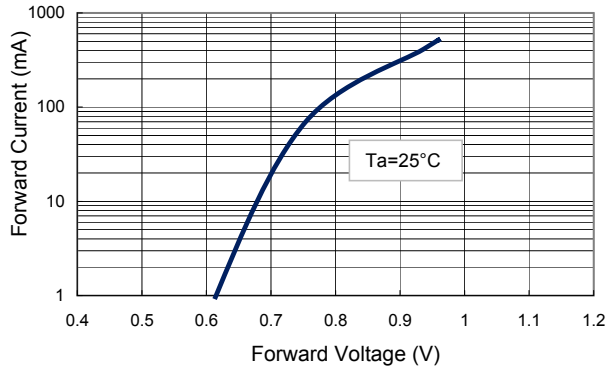
#### Notes:

1. The Zener Voltage (Vz) is tested under pulse condition of 10ms.
2. The device numbers listed have a standard tolerance on the nominal zener voltage of  $\pm 2\%$ .
3. For detailed information on price, availability and delivery of nominal zener voltages between the voltages shown and tighter voltage tolerances, contact your nearest **Taiwan semiconductor** representative.
4. The Zener impedance is derived from the 60-cycle ac volatge, which results when an ac current having an rms value equal to 10% of the dc zener current (IZT or IZK) is superimposed to IZT or IZK.

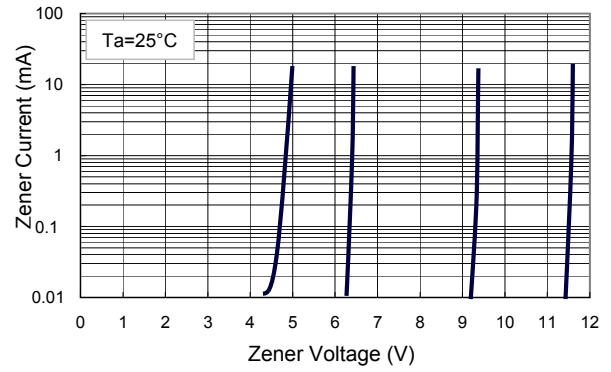
**Small Signal Diode**

**Rating and Sharacteristic Curves**

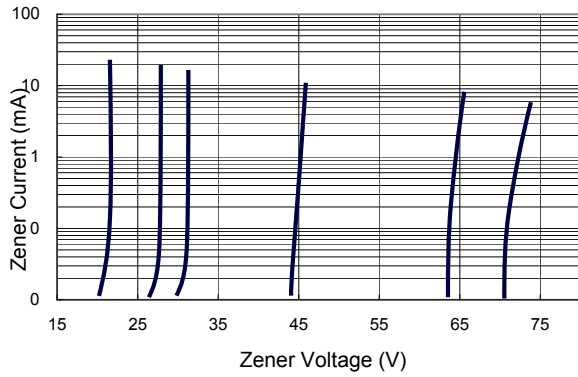
**FIG 1 Typical Forward Characteristics**



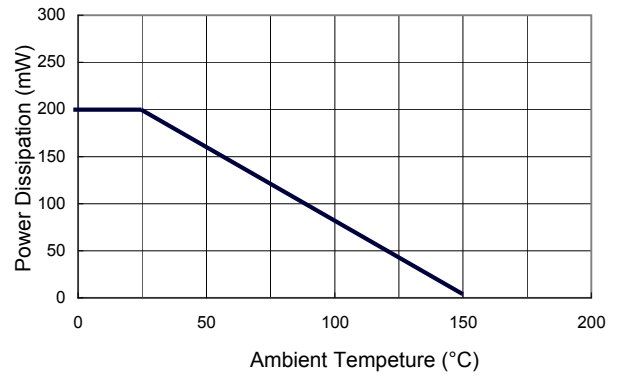
**FIG 2 Zener Breakdown Characteristics**



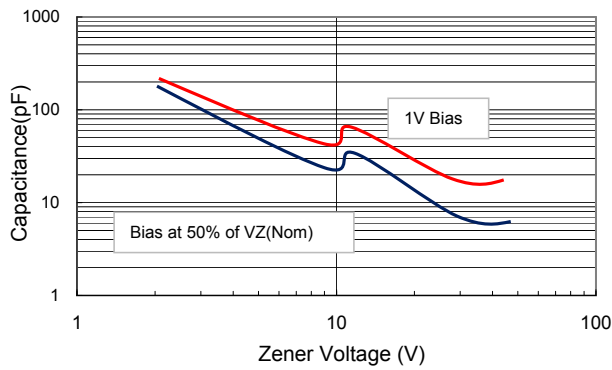
**FIG 3 Zener Breakdown Characteristics**



**FIG 4 Admissible Power Dissipation Curve**



**FIG 5 Typical Capacitance**



**FIG 6 Effect of Zener Voltage on Impedance**

